Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	769	257/417.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/17.08:58
S2	6	("4411741" "5911873" "4385274").pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:51
S3 -	2	"EP 947829"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:18
S4	2	"DE 4239319"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:21
S5	5	"DE 3144459"	US-PGPUB;	OR	ON	2005/08/10 14:29
	0		USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			. X
S6	1	"DE 19849932"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/10 14:30
S7	16362	sensor and (air adj gap)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 09:12
S8	53	S7 and (guard adj ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:48

S22	334627	substrate near surface	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 09:22
S23	36450	S22 and insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 09:22
S24	8688	S23 and (rings or ridges or elevations)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 09:42
S25	86	S24 and (surface near conductivity)	US-PGPUB;	OR	ON	2005/08/11 09:22
			USPAT; USOCR;			
			EPO; JPO;			
1 4 × - 1			DERWENT; IBM_TDB			
S26	186	S23 and "insulator ring"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 10:00
S27	1897	73/23.2,31.06.ccls.	US-PGPUB;	OR	ON	2005/08/15 16:35
			USPAT; USOCR;			
			EPO; JPO; DERWENT;			
			IBM_TDB			
S30	18	air adj gap and 73/23.2,31.06.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/08/11 10:01
S31	3	("3584499" "4860574" "6430987").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/11 10:19
S33	33	air adj gap and 257/417.ccls.	US-PGPUB; USPAT; USOCR	OR	ON .	2005/08/11 10:19

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S34	261	chemfet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/08/12 14:46
S35	9	("4838088" "4930043" "4999735" "5006487" "5008774" "5025346" "5043043" "5121180" "5216490").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/11 10:52
S36	6950	257/417,108,415,418,327,252,253, 127,339,225,73,222,225,488, 489;73/23.2,31.06.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:55
S37	25	S36 and (air adj gap) and ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:19
S38	833	S36 and ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:19
S40	3061	S36 and (insulat\$3 ring) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:20
S41	10	S36 and (insulat\$3 adj ring) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:23
S42	1622	insulator adj ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:26
S43	100	insulator adj ring same substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:29

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S44	27296	insulat\$3 adj layer and ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:30
S45	5607	insulat\$3 adj layer and ring and sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON-	2005/08/11 11:30
**;			IBM_TDB			
S46	6731	insulat\$3 adj layer same ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 11:31
S47	443	insulat\$3 adj layer same ring same guard	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ÓN	2005/08/11:11:31
S48	70	insulat\$3 adj layer same ring same guard same channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 12:53
S49	329	"insulative rings"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR.	ON	2005/08/11 12:55
S50	40	SGFET	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 12:55
S51	28	("4671852").URPN.	USPAT.*	OR«	ON-	2005/08/11 13:06
S52	5	CCFET	USPAT	OR	ON	2005/08/11 13:10
S53	. 8	("6175394").URPN.	ŮSPAT.	OR	ON	2005/08/11 13:07
S54	4	("5126812" "5313836" "5417111" "5504356").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/11 13:08
S55	3654	guard adj ring	USPAT	OR	ON	2005/08/11 13:10
S56	88	(guard adj ring) and (air adj gap)	USPAT	OR	ON	2005/08/11 13:11

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S57	9616	257/417,108,415,418,327,252,253, 127,339,225,73,222,225,488, 489;73/23.2,31.06;73/23.2,31. 06;204/424,431, 432;340/634;324/464,465.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 13:32
S58	188	S57 and (guard adj ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 15:17
S59	2	"20050146007"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 15:11
S60	246	S57 and (insulat\$3 with ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 15:35
S61	332	S57 and (field adj plates)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 15:35
S62	2	("4764797").pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:31
S63	4	"EP 155726"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR-	ON	2005/08/11 16:18
S64	2	"DE 4333875"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:25

S65	2	"20020157950"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:38
S66	1576	Frerichs, Heinz-Peter	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 16:38
S68	22	"Frerichs, Heinz-Peter".in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:22
\$71	286	"increase surface resistance"	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	ON*	2005/08/12 08:39
1 K.T			DERWENT; IBM_TDB) \ = .	
S72	36039	pattern and substrate and (increase same resistance) and surface	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 08:40
S73	2694	S72 and (ring same structure)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 08:40
S74	9616	257/417,108,415,418,327,252,253, 127,339,225,73,222,225,488, 489;73/23.2,31.06;73/23.2,31. 06;204/424,431, 432;340/634;324/464,465.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 16:45
S75	35	S73 and \$74	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	ON	2005/08/12 08:40
			DERWENT; IBM_TDB			

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S76	2	"4764797".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:24
S77	4637734	ep "155726"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:24
S78	4	"ep 155726"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:32
S79	25	"surface conductivity" and S74	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR #	ON	2005/08/12 09:39
			DERWENT; IBM_TDB			
S80	276	"surface conductivity" and (elevation or island)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:42
S81	0	"surface conductivity" and (elevation or island) near (channel and ring)	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	ON	2005/08/12 09:43
			DERWENT; IBM_TDB	1		
S82	3	(elevation or island) near (channel and ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:43
S83	315323	(channel and ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON ·	2005/08/12 09:43

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S84	2714	(channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:43
S85	0	insulat\$3 near between near (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/08/12 09:44
S86	1	insulat\$3 near (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:44
S87	∦ 4 1	insulat\$4 near (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON	2005/08/12 09:44
			IBM_TDB		÷1.	
588	239	island and (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:44
S89	0	island near (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:44
S90	32	island same (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2005/08/12 09:51
S91	73	insulator same (channel and "guard ring")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:53

S92	5605	STI and barrier	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:53
S93	330	S92 and sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 09:54
S95	5802	chemical adj sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:18
S96	*: 11	S95 and (guard adj ring)	US-PGPUB; USPAT;	OR	ON	2005/08/12 14:19
×			USOCR;	¥10	}- 7₽,	· . *.
7.5			EPO; JPO; DERWENT; IBM_TDB	3,	*.	*
S97	21973	gas adj sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:20
S98	13	S97 and (guard adj ring)	US-PGPUB; USPAT;	OR	ON	2005/08/12 14:23
-,			USOCR;		**. *	
	i.		EPO; JPO; DERWENT; IBM_TDB	*	+ n - n + 1	() () () () () () () () () () () () () (
S99	9273	(guard adj ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:23
S10 0	2512	(guard adj ring) and (air gap)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:24

S10	171	(guard adj ring) and (air adj gap)	US-PGPUB;	OR	ON	2005/08/12 14:29
1	1/1	(guaru auj riiig <i>)</i> and (aii auj gap)	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OK .	, , , , , , , , , , , , , , , , , , ,	2003, 00, 12 17,23
S10 3	261	257/253.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:40
S10 4	4	("4054875" "5837562" "6049313" "6282352").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/12 14:32
S10	2	("6555856").URPN.	USPAT	OR	ON	2005/08/12 14:32
. 5		and the second	e de grande			
S10 6	173	257/252.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:40
\$10 7	261	chemfet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:46
S10 8	0	S107 and (guard adj ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:53
S10 9	94	S107 and ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:47
S11 0	6950	257/417,108,415,418,327,252,253, 127,339,225,73,222,225,488, 489;73/23.2,31.06.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 14:15

S11 1	6950	S110	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:53
S11 2	179	S110 and (guard adj ring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 15:01
S11 3	41	S112 and (gap or cavity)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 14:53
S11 4	2640	S110 and sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 15:01
S11 6	58	S114 and guard	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/12 15:02
S11 7	2	"20020157950"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:51
S11 8	99	("6013936" "5883424" "5382825" "5884943" "5769117" "6206976" "4349394" "4480429" "4521795" "4812756" "4837443" "4874714" "4881107" "4963819" "5223919" "5232009" "5311900" "5423126" "5430311" "5472284" "5538492" "5563757" "5775169" "5859450" "6028010" "6082003" "6111271" "6509203" "5427111" "4862016" "3798512" "4633289" "5043781" "5274263" "6225241" "6225241" "6399991" "6707128" "4504801" "5651048" "5030853" "5305269" "5384730" "5396457" "5489814" "6111475" "5698884" "5786620" "5885876" "5814869").pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:58

S11	52	resistive adj field adj plate	US-PGPUB;	OR	ON	2005/08/15 10:22
9			USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			
S12 0	.88	"conductive field plates"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:34
S12 1	129	"equipotential rings"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:34
S12 2	27075	(chemical or gas) adj sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ÖN	2005/08/15 10:49
S12 3	29	S122 and (suspended or floating) adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:49
S12.	14	("4306196" "4322687" "4462002" "4495470" "4725348" "4810973" "4987379" "4992755" "5233543" "5726597" "5793230" "5880614" [**] "6002355" "6445171").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 10:57
S12 5	2742	field with isolation with structure	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 10:59
S12 6	168	field adj isolation₂adj structure	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 10:58
S12 7	168	field adj isolation adj structure	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:01
S12 9	12270	shallow adj trench adj isolation	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:01
S13 0	716	S129 and sensor	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:10

S13	666	S130 and (gas or ion or chemical)	US-PGPUB;	OR	ON	2005/08/15 16:03
1	000	3130 and (gas or lon or chemical)	USPAT; USOCR	UK	ON	2005/06/15 16:03
S13 2	400	S131 and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON .	2005/08/15 16:04
S13 3	2	S129 and ((gas or ion or chemical) adj sensor)	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:11
S13 4	12173	((gas or ion or chemical) adj sensor)	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:11
S13 5	59202	((gas or ion or chemical) with sensor)	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:12
S13 6	13785	S135 and ring	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:12
S13 7	36101	ring adj structure	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:13
S13 8	405	S137 and S135	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:13
S13 9	302	S138 and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:22
S14 0	217	S139 and substrate	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/15 16:22
S14 1	1424	73/23.2.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 16:33
S14 3.	501	73/31.06.ccls. and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 16:35
S14 4	1094	257/417.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 16:46

S14 5	675	257/417.ccls. and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 16:46
S14 6	1	"4161744".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 13:49
S14 8	4469	semiconductor and surface and geometry and resistive and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 13:51
S14 9	109	semiconductor and (surface adj geometry) and resistive and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	. 2005/08/16 14:04
S15 0	525	73/31.06.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 13:54
S15 1	813	semiconductor and (surface adj geometry) and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 14:04
S15 2	813	semiconductor and (surface adj geometry) and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 14:04
S15 3	187	semiconductor and sensor and (surface adj geometry) and @ad<"20030101"	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 14:04
S15 4	262	257/488.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 14:15
S15 5	86	257/489.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:43
S15 6	825	257/415.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:55

S15 7	6956	257/417,108,415,418,327,252,253, 127,339,225,73,222,225,488, 489;73/23.2,31.06.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:56
S15 8	596	257/327.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:55
S15 9	154	257/127.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:56